## Features

- Wide input voltage range: $1.5 \mathrm{~V}-6 \mathrm{~V}$
- Low $\mathrm{R}_{\mathrm{DS}(\mathrm{ON}): ~}^{80 \mathrm{~m} \Omega \text { typical @ } 5 \mathrm{~V}}$
- Turn-on slew rate controlled
- AP2281-1: 1 ms turn-on rise time
- AP2281-3: 100us turn-on rise time with internal discharge
- Very low turn-on quiescent current: $\ll 1 u \mathrm{~A}$
- Fast load discharge option
- Temperature range $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$
- SOT26 and DFN2018-6: Available in "Green" Molding Compound (No Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)


## Description

The AP2281 slew rate controlled load switch is a single P-channel MOSFET power switch designed for high-side load-switching applications. The MOSFET has a typical $\mathrm{R}_{\mathrm{DS}(\mathrm{ON})}$ of $80 \mathrm{~m} \Omega$ at 5 V , allowing increased load current handling capacity with a low forward voltage drop. The turn-on slew rate of the device is controlled internally.

The AP2281 load switch is designed to operate from 1.5 V to 6 V , making it ideal for $1.8 \mathrm{~V}, 2.5 \mathrm{~V}, 3.3 \mathrm{~V}$, and 5 V systems. The typical quiescent supply current is only 0.01 uA .

## Applications

- Smart Phones
- PDA
- Cell Phones
- GPS Navigators
- PMP/MP4
- Notebook and Pocket PC


## Ordering Information



| Device | Package Code | Packaging (Note 2) | 7" Tape and Reel |  |
| :---: | :---: | :---: | :---: | :---: |
|  |  |  | Quantity | Part Number Suffix |
| (18) AP2281-1WG-7 | W | SOT26 | 3000/Tape \& Reel | -7 |
| (18) AP2281-3WG-7 | W | SOT26 | 3000/Tape \& Reel | -7 |
| (16) AP2281-1FMG-7 | FM | DFN2018-6 | 3000/Tape \& Reel | -7 |
| ®8, AP2281-3FMG-7 | FM | DFN2018-6 | 3000/Tape \& Reel | -7 |

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead free.html.
2. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf

## Pin Assignments


( Top View )


DFN2018-6

## Pin Description

| Pin Name | Pin Number |  | Description |
| :---: | :---: | :---: | :--- |
|  | SOT26 | DFN2018-6 |  |
| OUT | 1 | 5,6 | Voltage output pin. This is the pin to the P-channel MOSFET drain <br> connection. Bypass to ground through a 0.1uF capacitor. |
| GND | 2,5 | 4 | Ground. |
| EN | 3 | 3 | Enable input, active high |
| IN | 4,6 | 1,2 | Voltage input pin. This is the pin to the P-channel MOSFET source. <br> Bypass to ground through a 1 $\mu \mathrm{F}$ capacitor. |

Options

| Part Number | Slew Rate (typ) | Active pull down | Enable |
| :--- | :--- | :--- | :--- |
| AP2281-1 | 1ms | no | Active high |
| AP2281-3 | 100us | yes | Active high |

## Block Diagram



## Typical Application Circuit



## Absolute Maximum Ratings

| Symbol | Parameter | Ratings | Unit |  |
| :---: | :--- | :--- | :---: | :---: |
| ESD HBM | Human Body Model ESD Protection | 5 | KV |  |
| ESD MM | Machine Model ESD Protection | SOT26 | 500 | V |
|  |  | 450 | V |  |
| $\mathrm{~V}_{\text {IN }}$ | Input Voltage | 6.5 | V |  |
| $\mathrm{~V}_{\text {OUT }}$ | Output Voltage | $\mathrm{V}_{\text {IN }}+0.3$ | V |  |
| $\mathrm{~V}_{\text {EN }}$ | Enable Voltage | 6.5 | V |  |
| $\mathrm{I}_{\text {Ioad }}$ | Maximum Continuous Load Current | 2 | A |  |
| $\mathrm{~T}_{\mathrm{J}}$ | Operating Junction Temperature Range | $-40 \sim 125$ | ${ }^{\circ} \mathrm{C}$ |  |
| $\mathrm{T}_{\text {ST }}$ | Storage Temperature Range | $-65 \sim 150$ | ${ }^{\circ} \mathrm{C}$ |  |
| $\mathrm{P}_{\mathrm{D}}$ | Power Dissipation | SOT26 (Note 3, 4, 5) | 720 | mW |
|  | DFN2018-6 (Note 3, 4, 6) | 1410 | mW |  |

Notes: 3. $\mathrm{T}_{\mathrm{J}}, \max =125^{\circ} \mathrm{C}$.
4. Ratings apply to ambient temperature at $25^{\circ} \mathrm{C}$.

## Recommended Operating Conditions

| Symbol | Parameter | Min | Max | Unit |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\text {IN }}$ | Input voltage | 1.5 | 6.0 | V |
| $\mathrm{I}_{\text {OUT }}$ | Output Current | 0 | 2.0 | A |
| $\mathrm{~T}_{\mathrm{A}}$ | Operating Ambient Temperature | -40 | 85 | ${ }^{\circ} \mathrm{C}$ |

## Electrical Characteristics

$\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}\right.$, unless otherwise stated)

| Symbol | Parameters | Test Conditions | Min | Typ. | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{Q}}$ | Input Quiescent Current | $\mathrm{V}_{\text {EN }}=\mathrm{V}_{\text {IN }}, \mathrm{l}_{\text {OUT }}=0$ | - | 0.01 | 1 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {SHDN }}$ | Input Shutdown Current | $\mathrm{V}_{\text {EN }}=0 \mathrm{~V}$, OUT open | - | 0.01 | 1 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {LEAK }}$ | Input Leakage Current | $\mathrm{V}_{\text {EN }}=0 \mathrm{~V}$, OUT grounded | - | 0.01 | 1 | $\mu \mathrm{A}$ |
| $\mathrm{R}_{\mathrm{DS}(\mathrm{ON})}$ | Switch on-resistance | $\mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}$ |  | 80 | 100 | $\mathrm{m} \Omega$ |
|  |  | $\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}$ |  | 95 | 120 | $\mathrm{m} \Omega$ |
|  |  | $\mathrm{V}_{\text {IN }}=1.8 \mathrm{~V}$ |  | 160 | 210 | $\mathrm{m} \Omega$ |
|  |  | $\mathrm{V}_{\mathrm{IN}}=1.5 \mathrm{~V}$ |  | 210 | 280 | $\mathrm{m} \Omega$ |
| VIL | EN Input Logic Low Voltage | $\mathrm{V}_{\text {IN }}=1.5 \mathrm{~V}$ to 6 V |  |  | 0.4 | V |
| $\mathrm{V}_{\text {IH }}$ | EN Input Logic High Voltage | $1.5 \mathrm{~V} \leq \mathrm{V}_{\text {IN }} \leq 2.7 \mathrm{~V}$ | 1.4 |  |  | V |
|  |  | $2.7 \mathrm{~V}<\mathrm{V}_{\text {IN }}<5.25 \mathrm{~V}$ | 1.6 |  |  | V |
|  |  | $\mathrm{V}_{\text {IN }} \geq 5.25 \mathrm{~V}$ | 1.7 |  |  | V |
| $\mathrm{I}_{\text {SINK }}$ | EN Input leakage | $\mathrm{V}_{\text {EN }}=5 \mathrm{~V}$ | - |  | 1 | $\mu \mathrm{A}$ |
| $\mathrm{T}_{\mathrm{D} \text { (ON) }}$ | Output turn-on delay time | $\mathrm{R}_{\text {load }}=10 \Omega$ |  | 1 |  | $\mu \mathrm{S}$ |
| Ton | Output turn-on rise time | AP2281-1, $\mathrm{R}_{\text {load }}=10 \Omega$ |  | 1000 | 1500 | $\mu \mathrm{S}$ |
|  |  | AP2281-3, $\mathrm{R}_{\text {load }}=10 \Omega$ |  | 100 | 150 | $\mu \mathrm{S}$ |
| $\mathrm{T}_{\text {D(OFF) }}$ | Output turn-off delay time | $\mathrm{R}_{\text {load }}=10 \Omega$ |  | 0.5 | 1 | $\mu \mathrm{S}$ |
| $\mathrm{R}_{\text {DISCH }}$ | Discharge FET on-resistance | For AP2281-3 only, $\mathrm{V}_{\mathrm{EN}}=\mathrm{GND}$ |  | 65 | 100 | $\Omega$ |
| $\theta_{\text {JA }}$ | Thermal Resistance Junction-to-Ambient | SOT26 (Note 5) |  | 153 |  | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
|  |  | DFN2018-6 (Note 6) |  | 78 |  |  |
| $\theta_{\text {Jc }}$ | Thermal Resistance Junction-to-case | SOT26 (Note 5) |  | 29 |  | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
|  |  | DFN2018-6 (Note 6) |  | 19 |  |  |

Notes: 5. Test condition for SOT26: Device mounted on FR-4 substrate PC board, 2 oz copper, with minimum recommended pad layout.
6. Test condition for DFN2018-6: Device mounted on FR-4 2-layer board, 2 oz copper, with minimum recommended pad on top layer and 3 vias to bottom layer 1.0"x1.4" ground plane.

## Typical Performance Characteristics








## Typical Performance Characteristics (Continued)


(500 $\mu \mathrm{s} / \mathrm{div}$ )


Time ( $500 \mu \mathrm{~s} / \mathrm{div}$ )

AP2281-1 Turn-Off
$\left(\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=7 \Omega\right)$


AP2281-1 Turn-Off
$\left(\mathrm{V}_{\mathrm{IN}}=5 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \Omega\right)$


## Typical Performance Characteristics (Continued)




## Single Slew Rate Programmable Load Switch

## Application Note

## Input Capacitor

A $1 \mu \mathrm{~F}$ capacitor is recommended to connect between IN and GND pins to decouple input power supply glitch and noise. The input capacitor has no specific type or ESR (Equivalent Series Resistance) requirement. However, for higher current application, ceramic capacitors are recommended due to their capability to withstand input current surges from low impedance sources, such as batteries in portable applications. This input capacitor must be located as close as possible to the device to assure input stability and less noise. For PCB layout, a wide copper trace is required for both IN and GND.

## Output Capacitor

A $0.1 \mu \mathrm{~F}$ capacitor is recommended to connect between OUT and GND pins to stabilize and accommodate load transient condition. The output capacitor has no specific type or ESR requirement. The amount of the capacitance may be increased without limit. For PCB layout, the output capacitor must be placed as close as possible to OUT and GND pins, and keep the traces as short as possible.

## ENABLE/SHUTDOWN Operation

The AP2281 is turned on by setting the EN pin high, and is turned off by pulling it low. To ensure proper operation, the signal source used to drive the EN pin must be able to swing above and below the specified turn-on/off voltage thresholds listed in the Electrical Characteristics section under $\mathrm{V}_{\text {IL }}$ and $\mathrm{V}_{\text {IH }}$.

## DISCHARGE Operation

The AP2281-3 offers discharge option that helps to discharge the output charge when disabled.

## Power Dissipation

The device power dissipation and proper sizing of the thermal plane is critical to avoid thermal shutdown and ensure reliable operation. Power dissipation of the device depends on input voltage and load conditions and can be calculated by:

$$
\begin{equation*}
P_{D}=I_{O U T}{ }^{2} \times R_{D S O N} \tag{1}
\end{equation*}
$$

However, the maximum power dissipation that can be handled by the device depends on the maximum junction to ambient thermal resistance, maximum ambient temperature, and maximum device junction temperature, which can be approximated by the equation below:

$$
\begin{equation*}
P_{D}\left(\max @ T_{A}\right)=\frac{\left(+125^{\circ} \mathrm{C}-\mathrm{T}_{\mathrm{A}}\right)}{\theta_{\mathrm{JA}}} \tag{2}
\end{equation*}
$$

For example at $\mathrm{V}_{\mathbb{I N}}=5 \mathrm{~V}$, the typical $\mathrm{R}_{\mathrm{DSON}}=80 \mathrm{~m} \Omega$. For lout $=2 A$, the maximum power dissipation calculated using equation (1) is $P_{D}=0.32 \mathrm{~W}$. Based on SOT26 $\theta_{\mathrm{JA}}=153^{\circ} \mathrm{C} / \mathrm{W}$ and equation (2), the calculated junction temperature rise from ambient is approximately $49^{\circ} \mathrm{C}$. Since the maximum junction temperature is $125^{\circ} \mathrm{C}$, the operating ambient temperature must be kept below $76^{\circ} \mathrm{C}$ to safely operate the device.

On the other hand, at $\mathrm{T}_{\mathrm{A}}=85^{\circ} \mathrm{C}$ and $\mathrm{V}_{\text {IN }}=5 \mathrm{~V}$, the calculated maximum power dissipation from equation (2) is approximately $P_{\text {Dmax }}=0.26 \mathrm{~W}$. Hence the safe operating maximum continuous current is 1.81A. For other application conditions, the users should recalculate the device maximum power dissipation based on the operating conditions.

## Marking Information

(1) SOT26

## ( Top View )



XX : Identification code
$\underline{Y}$ : Year 0~9
W : Week : A~Z : 1~26 week; a~z : 27~52 week; z represents 52 and 53 week
X : A~Z: Green

| Device | Package type | Identification Code |
| :---: | :---: | :---: |
| AP2281-1W | SOT26 | U2 |
| AP2281-3W | SOT26 | U3 |

(2) DFN2018-6

## ( Top View )

|  | XX : Identification code |
| :---: | :---: |
| XX | $\underline{Y}$ : Year 0~9 |
| $\underline{Y} \underline{\mathbf{W}} \underline{X}$ | W : Week: A~Z : 1~26 week; a~z: 27~52 week; z represents 52 and 53 week |
|  |  |
|  |  |


| Device | Package type | Identification Code |
| :---: | :---: | :---: |
| AP2281-1FM | DFN2018-6 | UE |
| AP2281-3FM | DFN2018-6 | UF |

## Package Information

(1) Package type: SOT26


## Package Information (Continued)

(2) Package type: DFN2018-6


## Taping Orientation



Notes: 7. The taping orientation of the other package type can be found on our website at http://www.diodes.com/datasheets/ap02007.pdf

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